W etting at Curved Substrates: N on A nalytic B ehavior of Interfacial P roperties

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A bstract. { We argue that for complete wetting at a curved substrate (wall) the wall- uid surface tension is non-analytic in R_i^{1} , the curvature of the wall and that the density probe of the uid near the wall acquires a contribution proportional to the gas-liquid surface tension R_i^{1} plus higher-order contributions which are non-analytic in R_i^{1} . These predictions are confirmed by results of density functional calculations for the square-wellm odel of a liquid adsorbed on a hard sphere and on a hard cylinder where complete wetting by gas (drying) occurs. The implications of our results for the solvation of big solvophobic particles are discussed.

Understanding the adsorption of uids at solid substrates has taken on new importance with recent advances in the controlled fabrication of tailored surfaces for applications in micro uidics and other areas []. Much experim ental [2] and theoretical e ort [3] is concerned with wetting and associated interfacial transitions in wedge geometry and recently attention has turned to wetting at an apex [4]. It is becoming increasingly clear that substrate geom etry can have a profound in uence on the nature of uid adsorption and, in particular, on wetting characteristics making these quite di erent from those at a planar substrate. Here we consider complete wetting at two substrates that have simple geometries, namely a single sphere of radius R_s and an in nitely long cylinder of radius R_c. Using an e ective interfacial Ham iltonian approach [5] combined with exact microscopic sum -rules for the density pro le of the uid near a hard wall, we show that in the limit $R_i \leq 1$, with i = s;c, the surface tension of the substrate (wall) – uid interface is non-analytic in the curvature R_i^{-1} and that the density of the uid in contact with the hard wall acquires a contribution proportional to $_{q1}(1) = R_{i}$, where $_{q1}(1)$ is the surface tension of the planar interface between coexisting gas and liquid, as well as higher-order non-analytic terms in R_i¹. Our results, which are con med fully by the results of microscopic density functional (DFT) 6] calculations, show that non-zero curvature leads to unexpected and subtle e ects on interfacial properties when com plete wetting occurs, even for the sim plest of substrate geom etries.

In previous theoretical studies of wetting on spheres and cylinders [7,8,9,10] the thrust was on understanding how a nite radius limits the thickness of a wetting limit and modil es the

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wetting transition that can occur at a planar substrate. Little attention was paid to the e ect of curvature on the surface tension and on the form of the density pro le near the substrate which are the main concerns of this Letter. Our results have repercussions for the general theory of solvation of big solvophobic solute particles, for wetting of colloidal particles and bers [,10] and, possibly, for the surface tension of drops and bubbles [11].

We consider rst the general case of a bulk uid phase a, at chem ical potential, in contact with a wall w and implement a standard, coarse-grained, e ective interfacial H am iltonian approach [5,8] in which the wetting lm of uid phase b is characterized only by its thickness 1. For short-ranged (nite ranged, exponentially or faster decaying) wall- uid and uid- uid potentials the binding potential, i.e. the excess (over bulk) grand potential per unit area, takes the form [5,8]:

$$k_{wa}^{i}(l) = k_{wb}^{i}(R_{i}) + k_{ba}^{i}(R_{i}+l) + a(T)e^{l} + (a_{a}b) + l + \frac{k_{ba}^{i}(R_{i}+l)l}{R_{i}} + O(l=R_{i})^{2}; \quad (1)$$

with i = s; c and s = 2, c = 1 for the spheres and cylinders, respectively. $\frac{1}{wb}$ is the surface tension of the wall-phase b interface, $\frac{i}{ba}$ is the tension of the ba uid uid interface located near $R_i + l, \alpha(T) > 0$ is a coe cient that we need not specify further for complete wetting, is the true bulk correlation length of the wetting phase b. The fourth term in eq. () and accounts for the increase in grand potential per unit area associated with the volum e of a Im of phase b; $_{co}$ (T) is the chem ical potential deviation and $_{a, b}$ are the number densities of bulk phases a and b at coexistence $_{co}$ (T). For $R_i = 1$ the binding potential (1) reduces to that appropriate for complete wetting at a planar interface in models where the range of the wall- uid potential is shorter than and, henceforward, we shall assume this is the case. Then m inim izing eq. (1) w.r.t. 1 yields the well-known logarithm ic divergence In thickness: l_q (1) = _b)=a(T)), as of the equilibrium 6 ! O. W hen ln ($R_i \in 1$ two important modi cations arise: i) $_{wb}^i$ and $_{ba}^i$ now depend on curvature and ii) the surface area of the bainterface now depends on the Im thickness 1. Equation 1) assumes very large radii R_i and that $l=R_i$ 1. Note that the flat term in 1 is proportional to the Laplace pressure across the uid-uid ba interface. Since ba is always non-zero, away from the bulk critical point, this term ensures that the $\,$ lm thickness remains $\,$ nite even at $_{\infty}$ (T), i.e. m in in izing eq. (1) yields $l_{eq}^{i}(R_{i}) =$ $\ln \begin{bmatrix} i \\ ba \end{bmatrix}$ (R_i)=(R_ia(T))] for = 0, where wehave ignored term s 0 $(l=R_i)^2$ and the l dependence in i_{ba} { this can be justified a posteriori. Several authors [7,8,9,10] have argued that for large R $_{\rm i}$ the quantity $_{\rm i}$ $_{\rm ba}^{\rm i}$ (R $_{\rm i}$)=R $_{\rm i}$ should play the same role in complete wetting at a curved wall, with = 0, as the e ective bulk eld plays for the planar wall. We shall pursue this argum ent further in the present (a ь) Letter.

The wall- uid surface tension is given by

$${}^{i}_{wa}(R_{i}) \qquad {}^{i}_{wa}(l_{eq}) = {}^{i}_{wb}(R_{i}) + {}^{i}_{ba}(R_{i}) + (+ l_{eq}) \qquad {}^{i}_{ba}{}^{i}_{ba}(R_{i}) + (_{a} _{b}) \qquad : (2)$$

For the planar interface the naltern vanishes at = 0 and the wall-uid tension reduces to the sum of the planar tensions: $_{wa}(1) = _{wb}(1) + _{ba}(1)$, appropriate to complete wetting by a macroscopic lm of phase b. When $\Leftrightarrow 0$, $_{wa}(1)$ acquires a non-analytic contribution proportional to j jln j j5]. For nite R_i we set = 0 and obtain

term s in eq. (3). At the non-wet wb interface we do not expect non-analyticities in $\frac{1}{Wb}(R_i)$, provided the system exhibits short-ranged forces [12]. For a spherical uid- uid interface it is usually assumed [11] (for short-ranged forces) that

$$_{ba}^{s}(R_{s}) = _{ba}(1)(1 2_{T}^{s} = R_{s} + H O : T :);$$
 (4)

where T_T^s is the Tolm an length [13] fam iliar in studies of liquid drops, whereas for cylindrical interfaces it has been argued [14] that

$$c_{ha}(R_c) = b_{a}(1)(1 + b_{H} \ln R_c = R_c + H O : T :):$$
 (5)

If the latter form were correct eq. (3) would imply that the wall-uid tension ${}_{wa}^{c}(R_{c})$ should have a contribution ${}_{ba}(1)(b_{H} +)\ln(R_{c})=R_{c}$. Provided the length b_{H} is comparable with the bulk correlation length , as is expected on physical grounds, the term in b_{H} should be easily identied in numerical work.

The result (3) is valid for any complete wetting situation, with the proviso that the forces are short-ranged. We specialize now to the case of a hard wall exerting a purely repulsive potential on the uid: $V_i(r) = 1$ for radius $r < R_i$ and is zero for $r > R_i$. It is well-known that the phenom enon of complete drying occurs at a planar hard wall: the interface between the bulk liquid (1) and the wall is wet by a macroscopic lm of gas (g) as $! \stackrel{+}{_{co}}(T)$ for all tem peratures T at which gas and liquid coexist [15,16]. At $= \stackrel{+}{_{co}}(T)$ the density prole of the uid is a composite of the planar wall-gas and the (free) gas-liquid interfacial proles and $w_1(1) = w_g(1) + g_1(1)$; phase a l and phase b g. W hilst drying at a planar hard wall has been investigated extensively using computer simulations [15] and DFT [16], we are not aware of studies on curved substrates. We shall see below that curvature leads to some estriking new results. When $R_i \in 1$ thick lm s of gas will still develop at the wall but the thickness will remain nite at $\stackrel{+}{_{co}}(T)$ and the wall-liquid tension $\stackrel{i}{w_1}(R_i)$ should exhibit the non-analyticities described above. Moreover the density prole (r) is no longer a perfect com posite of the two separate interfacial proles and exhibits interesting features near the wall.

A particular advantage of hard walls is that there is an exact statistical mechanical sum – rule [17] which relates the uid density at contact, ${}^{i}(R_{i}^{+})$, to the pressure p of the bulk (reservoir) uid and the wall-uid tension:

$$k_{\rm B} T^{i} (R_{i}^{+}) = p + \frac{i_{\rm wf}^{i} (R_{i})}{R_{i}} + \frac{\underline{\theta}_{\rm wf}^{i} (R_{i})}{\underline{\theta} R_{i}}^{i} : \qquad (6)$$

In the limit $R_i = 1$ the contact density reduces to $p=k_B T$, the well-known planar contact theorem. Equation (6) is valid for any one-component uid at a hard wall. We now insert our result (3) for the tension of the Ury' interface, ${i \atop w1}(R_i)$, into (6) to obtain the contact density ${i \atop liq}(R_i^+)$ at $={i \atop co}(T)$. By subtracting ${i \atop gas}(R_i^+)$, the contact density when the bulk phase is gas at $={i \atop co}(T)$, we eliminate both the pressure $p(_{co})$ and the (analytic) wall-gas tension obtaining for a hard spherical wall:

$$k_{\rm B} T \left({}^{\rm s}_{\rm liq} \left({\rm R}_{\rm s}^{\, +} \right) \right) = \frac{2_{\rm gl} \left(1 \right)}{{\rm R}_{\rm s}} + \frac{2_{\rm gl} \left(1 \right)}{{\rm R}_{\rm s}^{\, 2}} \ln {\rm R}_{\rm s} + {\rm H} \ \mathfrak{O} \ \mathfrak{T} : \tag{7}$$

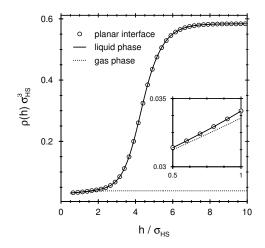


Fig. 1 { The density professor is a square-well wide adsorbed at a hard wall for kT = " = 1. Solid curve refers to a liquid at bulk coexistence $c_{co}^{+}(T)$ near a spherical wall of radius $R_s = 2500_{HS}$ and the dotted curve to the gas at $c_{co}(T)$ at the same wall. Symbols refer to the liquid near a planar wall at chemical potential $c_{co}(T) = 2_{g1}(1) = (R_s(1 - g))$ (see text). One observes that the two wall-liquid professor is an explanate in the region of the gas-liquid interface and close to the wall { see inset. Contact occurs at distance h = $_{HS} = 2$.

and for a hard cylindrical wall:

$$k_{\rm B} T \left({}^{\rm c}_{\rm liq} \left({\rm R}_{\rm c}^{\, +} \right) \right) = \frac{{}^{\rm gl}(1)}{{}^{\rm R}_{\rm c}} + \frac{\left({}^{\rm +}{}^{\rm b_{\rm f}} \right) {}^{\rm gl}(1)}{{}^{\rm R}_{\rm c}^{\, 2}} + {}^{\rm H} \mathfrak{O} : T:$$
(8)

where H Ω ff: refers to term s of higher order in R_i^{-1} . For a planar wall the contact density is p($_{\rm CO}$)=k_B T in both phases so the di erence vanishes identically. There are two remarkable features in these results. First the contact density in the liquid phase (dry' interface) depends on $_{\rm gl}(1)$, the tension of the planar gas-liquid interface, which can be very far from the wall as R_i ! 1 : the rst term on the rhs. of 7) and (8) is simply the Laplace pressure across the gas-liquid interface. Second the contact density di erence for the sphere contains a next to leading order $R_s^{-2} \ln R_s$ non-analyticity, whereas for the cylinder the next to leading order term is analytic, i.e. O (R_c^{-2}), despite the fact that both surface tensions are non-analytic at order $R_i^{-1} \ln R_i$.

In order to test the predictions of the coarse-grained theory we have adopted a fully m icroscopic DFT approach and perform ed calculations for a square-well uid at hard curved walls. The uid-uid pair potential (r) is in nite for $r <_{HS}$, the hard sphere diam eter, the width of the well is 0.5_{HS} and the well-depth is ". We treat the hard-sphere part of the free-energy functional by means of Rosenfeld's fundam ental measure theory [18] and the attractive part using a simple mean- eld approximation (, 16], taking $_{att}(r) =$ " for $r < 1.5_{HS}$ and zero otherwise. By minimizing the grand potential functional we determ ine the equilibrium density pro le (r) and the wall-uid tension for any therm odynamic state; details of the numerical treatment will be given elsewhere. Our DFT approach has the following advantageous features: i) the coexisting densities of gas and liquid, $_{g}$ and $_{1}$, can be calculated precisely, ii) the DFT obeys the sum-rule (6) and the G ibbs adsorption theorem and iii) the key quantities and $_{g1}(1)$ which enter eqs. (3,7,8) can be obtained from independent calculations (for the bulk and for the planar interface) using the same functional.

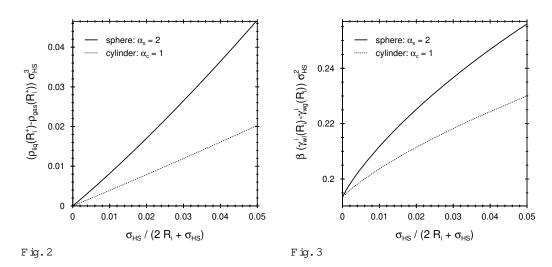


Fig. 2 { The di erence between contact densities of a square-well uid in the liquid and in the gas phases, at $_{co}$ (T), adsorbed at a hard spherical (full line) and hard cylindrical (dotted line) wall of radius R_i for k_B T=" = 1. From the linear portion of each curve near the origin, we can extract the gas-liquid surface tension $_{g1}(1)$. The next to leading order term is proportional to R_s² ln R_s for the sphere and to R_c² for the cylinder { see eqs. (7) and (8).

Fig. 3 { As in g.2 but now for the di erence between the surface tensions. For both geometries the leading order curvature dependence is proportional to $\ln R_i = R_i$ { see eq. (3). In both cases the coe cient is con rm ed to be $_i$ $_{g1}(1) = k_B T$, with the correlation length in the bulk gas.

We focus rst on the density pro le. In gl we display results for (r), at a reduced tem perature $k_B T = 1$ and chem ical potential $_{co}^+$ (T), for the square-well uid adsorbed on a hard sphere with madius $R_s = 2500_{HS}$. In the same gure we show the pro les for the wall-gas interface at $_{co}$ (T) and for the planar interface with $_{co}$ (T) = 2 $_{gl}(1) = (R_s(_{1 g}))$. O ne can observe that this translation between bulk eld for a planar wall and curvature yields wall-liquid pro les which lie on top of each other. This is a non-trivial result. Although it is evident that within the coarse-grained treatment of eq. (1) the lm thickness $_{eq}^{i}$ is identical for planar and curved walls, there is no reason a priori why the com plete m icroscopic density pro les should be especially close.

In g.2 we seek to test the validity of eqs. (7, 8) by examining the di erence in the contact densities for the two phases as a function of R_i^{-1} . Our DFT results are in excellent agreement with the prediction of the coarse grained theory for both spheres and cylinders. In particular we nd the data is t best with a $R_s^2 \ln R_s$ contribution for spheres and without such a contribution for cylinders. It is straightforward to extract the coe cient of the R_i^{-1} contribution and we nd close agreement, to 1 part in 10⁴, with our independent (planar) results for the dimensionless quantity $i_{gl}(1) j_{R_s}^2 = k_B T$.

In g.3 we plot the di erence between the wall-liquid and wall-gas surface tensions, evaluated at $_{co}$ (T), respectively versus R_i¹ for the square-well uid adsorbed at spheres and cylinders, again for k_B T = " = 1. In accordance with eqs. (3) and (4) we expect that for the sphere the leading order curvature correction to the di erence is proportional to R_s¹ ln R_s with a coe cient given by 2 $_{g1}(1)$ where is the correlation length in the bulk gas. For cylinders we employ eqs. (3) and (5) which in ply the same type of leading order correction but now with a coe cient (+ b_R) $_{g1}(1)$. Our num erical DFT results are completely consistent

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with these predictions with the relevant coe cients agreeing with the planar result to better than 1%. In our calculations we were able to obtain reliable results for R_s up to 30000 $_{\rm H\,S}$ and R_c up to 5000 $_{\rm H\,S}$. For the cylinder our best tyields a coe cient that has $l_{\rm p}=0$ (or a very small fraction of) and we conclude that there is no evidence for the $\ln R_c=R_c$ term conjectured [14] for the cylindrical uid-uid interface { see eq.50. We have con med that the same level of agreem ent between the coarse-grained theory and DFT holds at other tem peratures.

Since there is nothing special about the square-wellm odel our predictions for hard spheres and cylinders should be valid for any uid with short-ranged uid-uid potentials that exhibits gas-liquid coexistence and this has in portant repercussions for the solvation of big solvophobic solute particles. The excess chem ical potential of a single hard sphere of radius R_s in a solvent is given generally by $\sim^{H S} (R_s) = p4 R_s^3 = 3 + \sum_{w f}^{s} (R_s) 4 R_s^2$, where $\sum_{w f}^{s} s$ is the wall-uid surface tension. U sing eq. (3) it follows that the di erence between $\sum_{w f}^{H S} evaluated in the liquid, where drying occurs, and in the gas phase, at <math>\sum_{w c} (T)$, is

$$\frac{(\sim_{\text{liq}}^{\text{H S}} \quad \gamma_{\text{gas}}^{\text{H S}})}{4 R_{\text{s}}^2} = _{g1}(1)(1+2 R_{\text{s}}^{-1} \ln R_{\text{s}}) + H \mathfrak{O} \mathfrak{T}; \qquad (9)$$

for R_s ! 1. W hilst it is known from recent studies [19] of hard-sphere solutes that $\sim_{liq}^{H_s}$ should contain a gas-liquid surface tension contribution $_{g1}(1) 4 R_s^2$, the presence of the non-analytic correction is striking { especially when we recall that the excess chem ical potential is the derivative of the excess free energy of the bulk m ixture w r.t. the solute density in the lim it of vanishing solute.

The coarse grained treatment that leads to eq. (3) is valid for wetting by either uid phase. Thus, provided the attractive part of the wall- uid potential is su ciently strong and has nite range or decays on a length scale that is shorter than the bulk correlation length , now referring to the wetting liquid, adsorption from the saturated gas, at $_{co}$ (C), will give rise to a wall-gas tension which has a term $_{i}$ $_{gl}(1)$ R $_{i}^{-1}$ ln R $_{i}$. A lthough the contact theorem (6) is modil ed when the wall- uid potential is no longer purely hard the contact density in the presence of a wetting liquid lin will still acquire term s which depend on the gas-liquid surface tension, i.e. we expect results equivalent to (7) and (8).

Both the coarse-grained and DFT approaches presented here are mean-eld like in that they om it elects of capillary-wave uctuations in the wetting $\ln 5_1$ [6]. For complete wetting in three dimensions at a planar interface, renormalization group studies based on elective interfacial H am iltonians with the binding potential (1) and that critical exponents are not altered from their mean-eld values but the amplitude of the equilibrium limethickness $l_{eq}(1)$ is changed from to (1 + ! = 2), for ! < 2, when uctuations are included5[]. Here $! = k_B T = (4 - g_1(1))^2$ is the usual parameter which measures the strength of capillary-wave uctuations: ! = 0 corresponds to mean-eld. We conjecture that our present results for the binding non-analytic term in the surface tension are modiled in a similar fashion, i.e. the third term in eq. (3) simply has replaced by (1 + ! = 2). As regards the results (7) and (8) for the dimensions whereas the next to leading order term in eq. (7) will require the same replacement for .

For real uids dispersion forces are always present giving rise to r⁶ power-law decay of the uid-uid pair potential. This leads, in turn, to a wetting lm thickness which diverges at coexistence as $l_{eq}(R_i) = R_i^{1=3}$, for $R_i \leq 1$ [10,20]. The present coarse-grained analysis suggests that the non-analyticities in curvature which arise for wetting with such potentials will be power laws rather than terms involving logarithms and we are presently investigating these using DFT [21].

We have shown that the isom orphism between bulk eld $(1 \ g)$ for a planar substrate and Laplace pressure at a curved substrate in plied by the binding potential (1) leads to striking consequences for interfacial properties: rst one cannot obtain the surface excess free energy (surface tension) of a uid that wets completely a non-planar substrate by expanding only in powers of the curvature(s). Second the true microscopic density prolenear the curved substrate depends on the surface tension of the gas-liquid interface which, for large R_i , can be far from the substrate. A detailed explanation of this curious behavior will be given elsewhere. Here we merely state that it is associated with the exponential decay (for short-ranged potentials) of the tails of the density prole of the 'free' gas-liquid interface. This is not the rst time that analysis of complete wetting or drying at a hard wall has caused surprises and lead to new insight into the fundam ental physics of uid interfaces [5,22].

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